

Abstract

The Johns Hopkins University Applied Physics Laboratory (JHU/APL) has developed photovoltaic fibers (PVFs) including interdigitated back contact (IBC) crystalline silicon (c-Si) solar cells as small as 0.35 mm^2 . The fiber was built on a flexible circuit strip as narrow as $400 \text{ }\mu\text{m}$ and the solar cell was surface mounted on the strip. The solar cells were cut out of the state-of-the-art IBC Si solar cell with power conversion efficiency (PCE) of about 22 % under AM1.5 irradiation. The PCE of the fiber has reached up to 11 % under AM1.5 after encapsulation and PCE is expected to improve with further optimization in solar cell dicing. The fiber did not show any performance loss after 8000 bending cycles with a bending radius down to 1 cm. The bending test was not performed until failure and the minimum bending radius is expected be on the order of millimeters. To demonstrate the practicality of the fiber technology, the fibers were woven into textiles powering a light-emitting diode. The c-Si PVF has been tested under AM0 irradiation and showed slightly higher PCE than when measured under AM1.5 irradiation. Together with its potential for flexible space solar power, the technology aligns well with current interest in Si solar cell technology for space power.

Flexible Space Solar Power

❖ Flexible photovoltaic textiles enable:

- Smart inflatable space structures with solar energy harvesting capability
 - Space stations
 - Lunar surface habitats – textile solar energy complements NASA's vertical solar array technology development roadmap
- Multifunctional electronics-integrated textiles (textronics)
- Low stowed launch volume

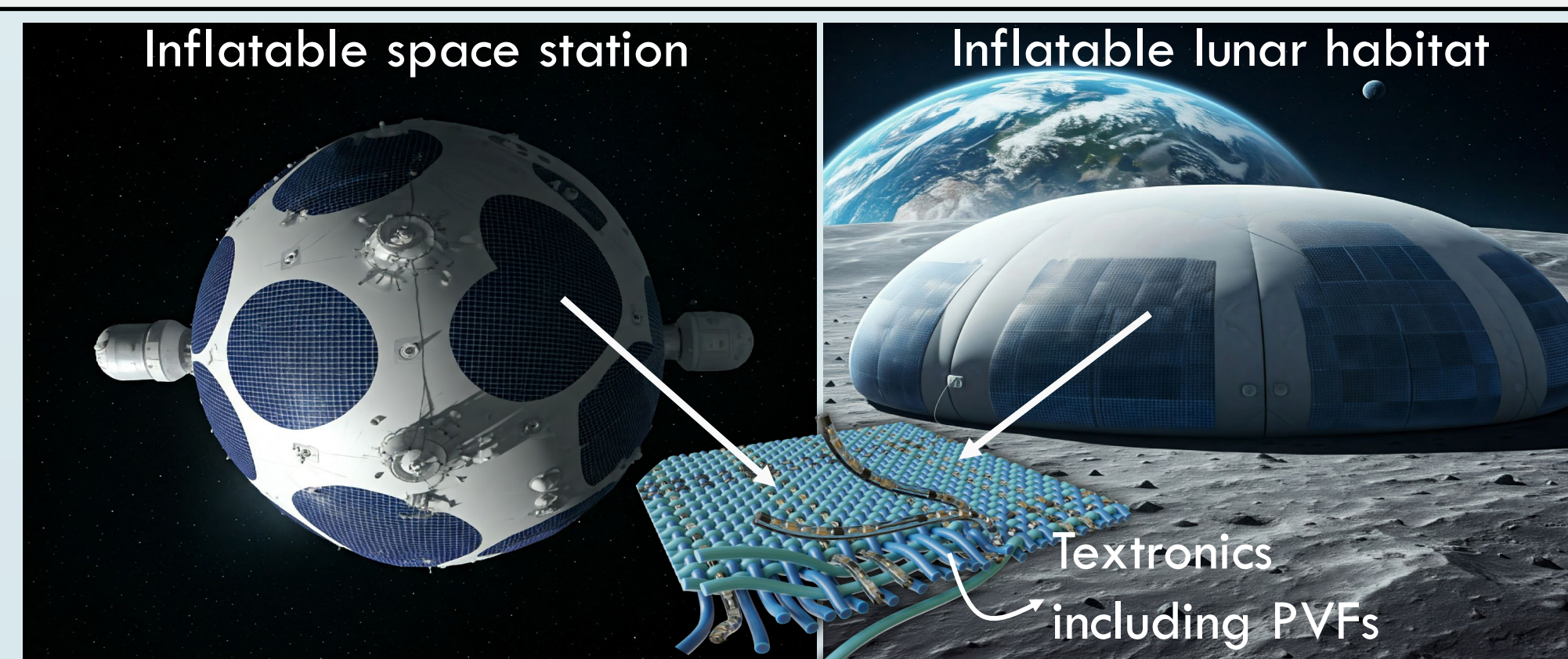


Figure 1: Examples of space application equipped with multifunctional textronics; the two application images were generated using Google Gemini from the prompt of an inflatable space station and an inflatable lunar habitat with flexible solar modules, respectively.

Fiber Technologies Developed by JHU/APL (Prior Work [1,2])

❖ Crystalline Silicon (c-Si) PVFs [1]

- Best PCE reported for c-Si PVFs: ~10%
- Scalable fabrication on $400 \text{ }\mu\text{m}$ -wide, 1.5'-long, flexible fiber substrates
- Leveraged mature IBC c-Si solar cell technology (SunPower C60 with PCE of 22%)
- Device-agnostic (any surface-mountable devices including PVs, batteries, LEDs, sensors, etc.)
- No performance loss after 8000 bending cycles at a bending radius down to 1 cm

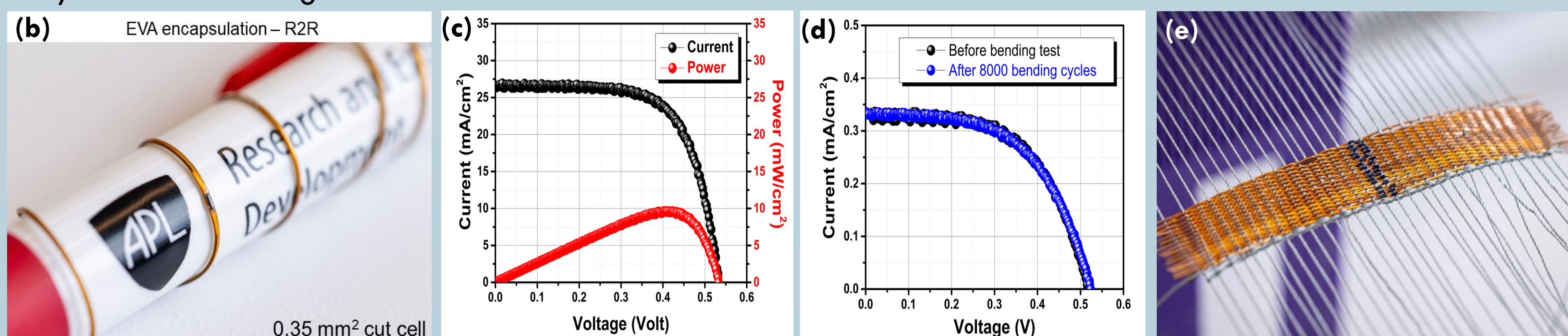


Figure 2: (a) Illustration of the c-Si PVF fabrication. (b) PVF with a single 0.35 mm^2 c-Si cell on a $400 \text{ }\mu\text{m}$ -wide fiber substrate, encapsulated with ethylene vinyl acetate (EVA) using a roll-to-roll (R2R) process. (c) Best PCE reported for c-Si PVF (1 mm^2 c-Si cell on a 1.5 mm-wide fiber substrate). (d) Power output characteristics of a c-Si PVF before and after bending fatigue. (e) PVFs (with 0.35 mm^2 c-Si cells) woven into a textile in a loom. Reproduced with permission [1]. Copyright 2024, Elsevier.

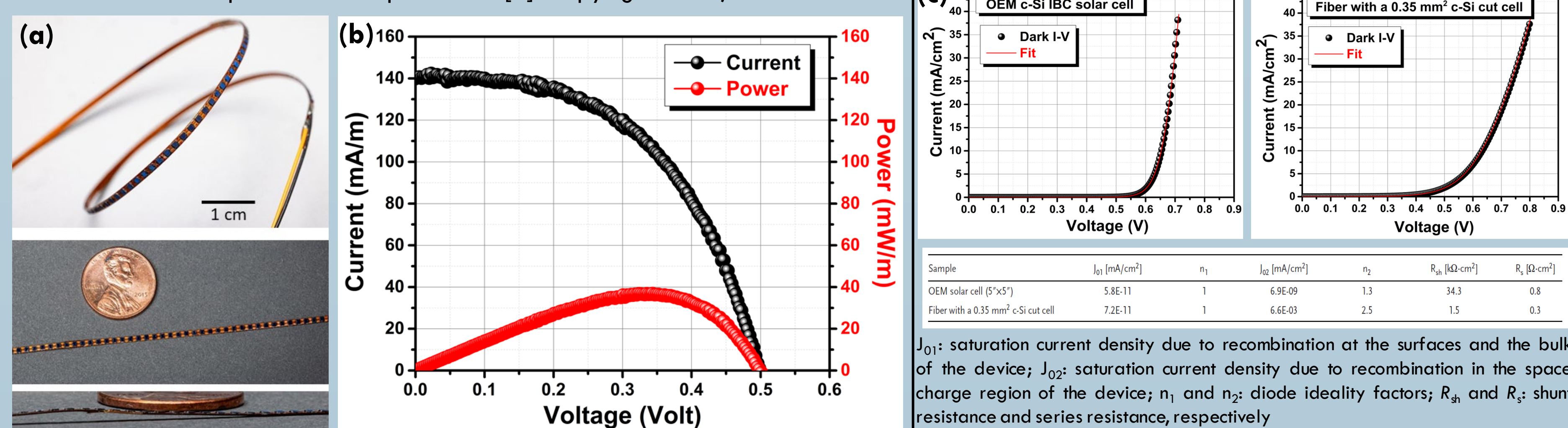


Figure 3: (a) A 1.5'-long PVF with 84 units of 1 mm^2 c-Si cell on a 1.5 mm-wide fiber substrate. (b) Power output characteristics of (a). (c) Dark I-V characteristics of a 153 cm^2 original equipment manufacturer (OEM) IBC solar cell and a fiber with a 0.35 mm^2 c-Si cell, fitted using a classic two-diode model, showing significant decrease in R_{sh} of the diced c-Si cell. Reproduced with permission [1]. Copyright 2024, Elsevier.

Scalable Fiber Fabrication

- Scalable fiber fabrication is possible with conventional industry tools such as a solder jet printer, a pick-and-place tool, and a laser cutter
- Parallel assembly processes such as micro-transfer printing, fluid assembly, chiplet printing, and laser-induced forward transfer can be explored to lower the cost of fabrication and to increase the throughput

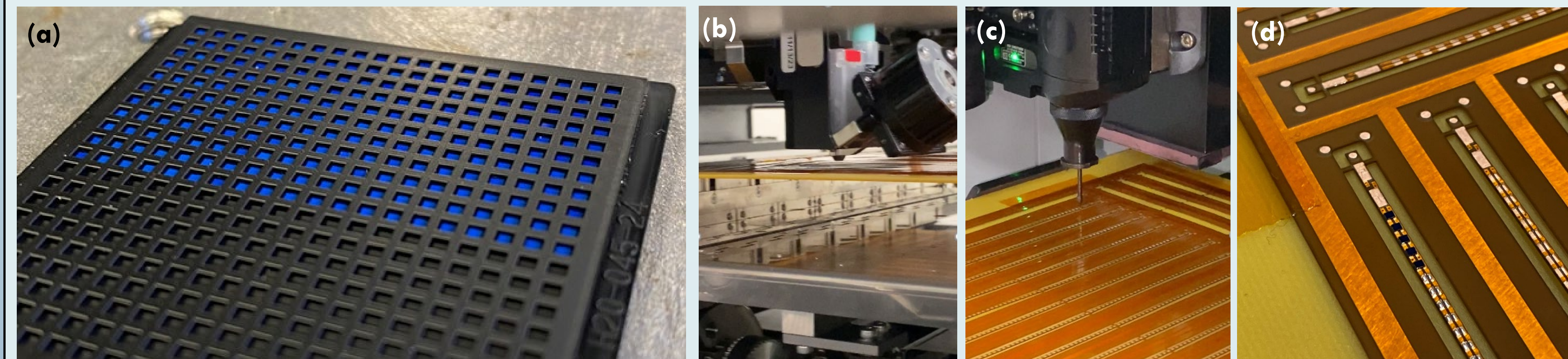


Figure 4: (a) 1 mm^2 c-Si cells in a pick-and-place compatible tray. (b) Solder jet printing process. (c) Pick-and-place process. (d) Fiber substrate board after the solder paste was reflowed in an oven and the fibers were mostly isolated from the board using a laser cutter.

c-Si PVF under AM0 Illumination

- PCE under AM0 irradiation was slightly higher than PCE under AM1.5 irradiation
- Slightly higher external quantum efficiency (EQE) at shorter wavelengths might have contributed to the higher PCE under AM0 irradiation

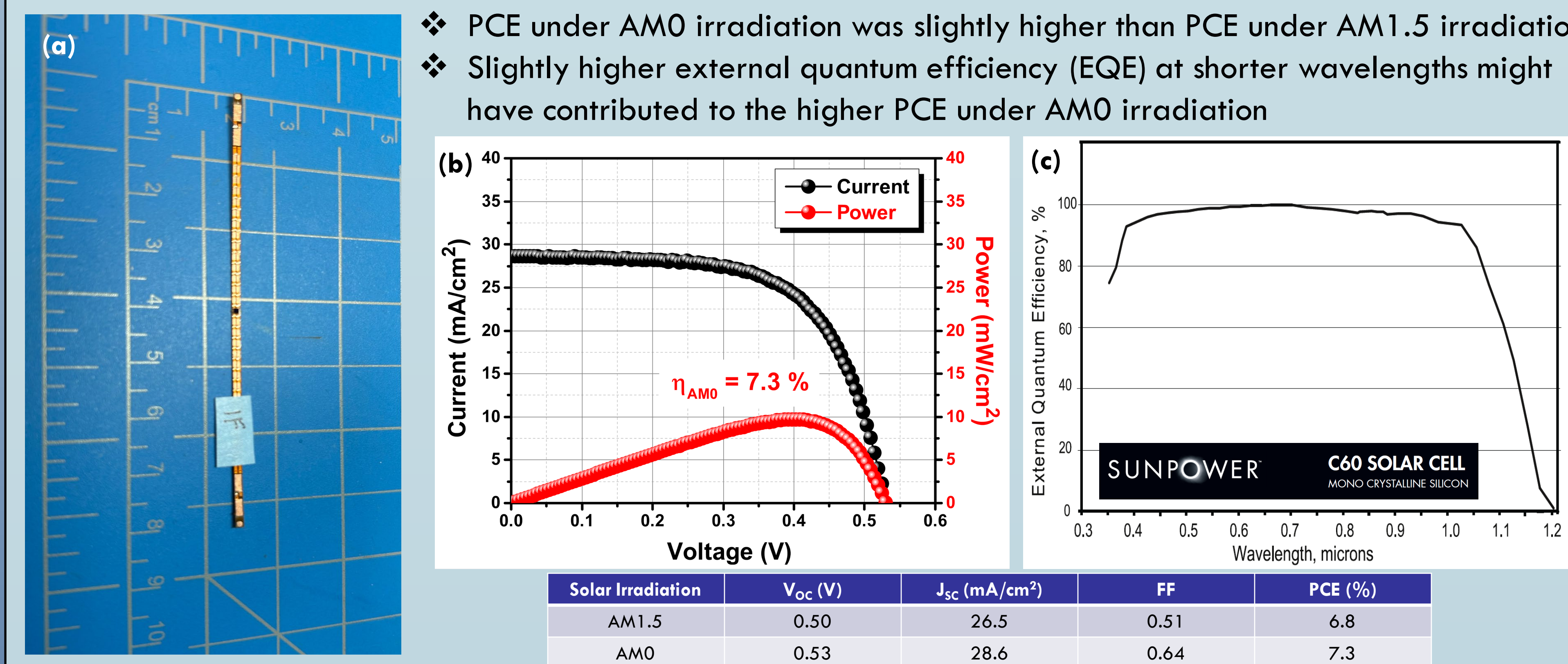


Figure 5: (a) c-Si PVF with a 1 mm^2 c-Si cell. (b) Power output characteristics of the PVF under AM0 irradiation; Rocket Lab's Z4J cell was used as a reference cell. (c) External quantum efficiency of SunPower's C60 solar cell from the vendor datasheet (https://solarmuseum.org/cells/284_sunpower/).

Stability of c-Si PVFs

- No performance loss from preliminary long-term stability and thermal cycling tests, reaffirming the maturity of the c-Si solar cell technology
- Fig. 6a: total energy the fiber received was $144 \text{ kWh}/\text{m}^2$, comparable to insolation expected for entire month of March at the Washington Dulles International Airport in US

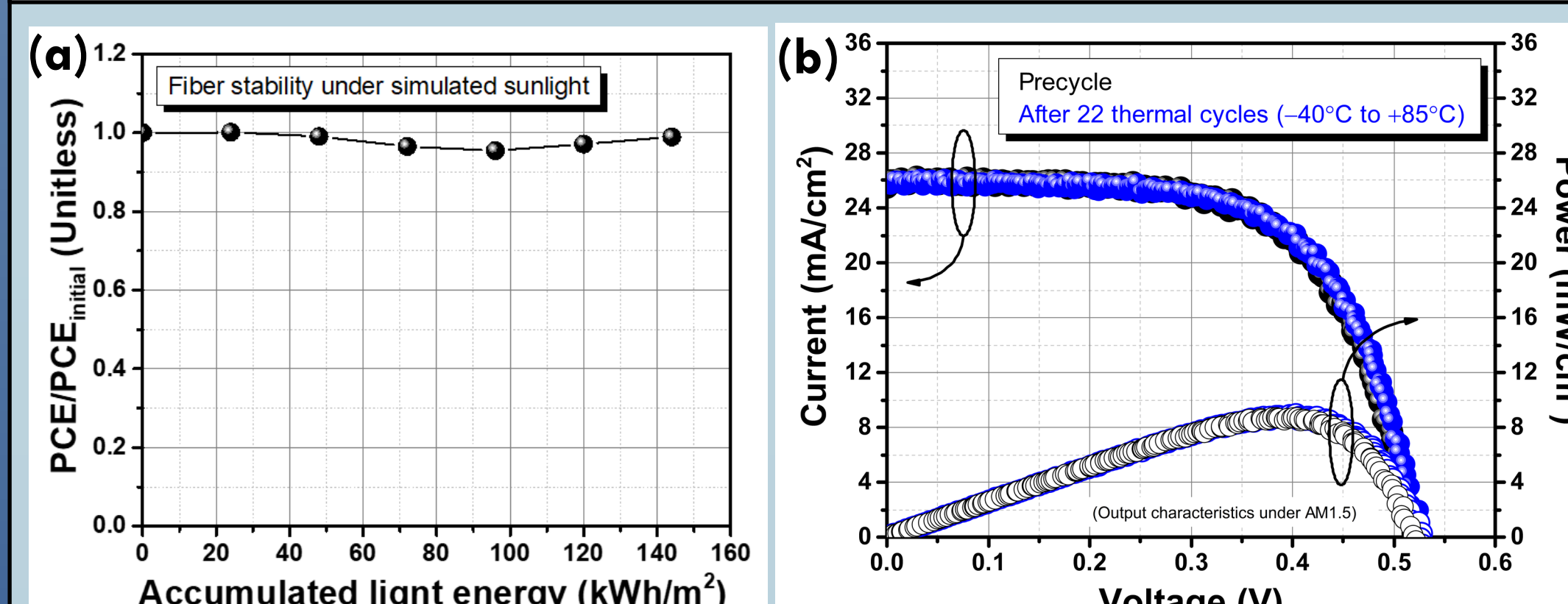


Figure 6: (a) Stability of a c-Si PVF exposed to a halogen lamp ($100 \text{ mW}/\text{cm}^2$) in a laboratory environment for six days. Reproduced with permission [1]. Copyright 2024, Elsevier. (b) Thermal cycle data collected from a c-Si PVF following a method outlined in IEC 61215.

Summary

- This work demonstrates an approach for achieving flexible space solar power using textile-based photovoltaic (PV) devices. This technology could enable new space structures such as inflatable space stations and inflatable lunar surface habitats with an integrated solar energy harvesting capability
- Device-agnostic fiber technologies developed by the Johns Hopkins University Applied Physics Laboratory can serve as the cornerstone of multifunctional textronics
- In this study, crystalline silicon PV fibers fabricated using a scalable process were characterized under AM0 irradiation and demonstrated no performance loss after thermal cycling testing

Acknowledgements

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